



Outline

FGT Physics motivation - W program

FGT Layout - Simulation results and optimization

FGT Technical Realization

- Triple-GEM detector development R&D
- Mechanical design
- O Front-End Electronics
- O DAQ

FGT Schedule / Milestones

Summary

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FGT



FGT Physics motivation - W program

Quark / Anti-Quark Polarization - W production



- Key signature: High p_T lepton (e⁻/e⁺ or 0 μ^{-}/μ^{+}) (Max. $M_{W}/2$) - Selection of
 - W⁻/W⁺: Charge sign discrimination of high p_T lepton
- Required: Lepton/Hadron 0 discrimination

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RHICBOS W simulation at 500GeV CME





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20 40 p_τ (GeV)



FGT Layout - Simulation results and optimization

Layout





 FGT: 6 light-weight triple-GEM disks - WEST side of STAR

New mechanical support structure

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FGT Layout - Simulation results and optimization

Quark / Anti-Quark polarization program at STAR - e/h separation

• Full PYTHIA QCD background and W signal sample including detector effects



 \circ e/h separation based on global cuts (isolation/missing E_T) and EEMC specific cuts as

• With current algorithm: E_T > 25GeV yields S/B > 1 (For E_T < 25GeV S/B ~ 1/5) used for A_L uncertainty estimates

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FGT Layout - Simulation results and optimization



Conclusion:

Charge sign reconstruction impossible beyond $\eta = \sim 1.3$

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6 triple-GEM disks, assumed spatial resolution 60 μ m in x and y (Fairly insensitive for 60-100 μ m)

Charge sign reconstruction probability above 90% for 30 GeV p_T over the full acceptance of the EEMC for the full vertex spread



SBIR proposal (1)

O SBIR: Small Business Innovation Research: US Government (DOE) funded program

Phase I: Explore feasibility of innovative concepts with award of up to \$100k

☑ Phase II: Principal R&D effort with award of up to \$750k

Phase III: Commercial application

• SBIR: Collaborative effort of Tech-Etch Inc. with BNL, MIT and Yale University - Production of GEM foils

Develop optimized production process for small (10cm X 10cm) and larger GEM foils

Investigate a variety of materials

Study post production handling: Cleaning, surface treatment and storage

O New SBIR proposal (submitted to DOE): 2D readout board using chemical etching



SBIR proposal (2)

O Tech-Etch Inc.: Company profile

□ Manufacturer of precision flexible circuits

Extensive experience in etching of copper traces and polyamide

Strong ties to BNL, MIT and Yale University

O Critical performance parameters

Achievable gain, gain uniformity and gain stability

Energy resolution

Tech-Etch Inc.



http://www.tech-etch.com

O Status

D Phase I / II approved - Dedicated production facility at Tech-Etch Inc.

Success with 10cm X 10cm samples / First large GEM foils received

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R&D Development at MIT

O Resources

2 dedicated clean rooms (Class ~100/1000) (MIT Bates Laboratory / MIT Laboratory for Nuclear Science)

HV radioactive source setup / HV box / Light-microscope / Laminar flow hood / GEM foil CCD camera scanner

O Activities based on 10cm X 10cm samples

- Dark current / resistivity tests
- Optical scans
- Sources tests and test beam experiment at FNAL

• Publications: 1) U. Becker et al., NIM A556 527 (2006). 2) F. Simon et al., IEEE Trans. Nucl.

Sci. 54, 2646 (2007). 3) F. Simon et al., NIM A598 432 (2009).

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- Prototype triple-GEM configuration (1)
 - O Prototype triple-GEM detector (Ar/CO₂

70:30 gas-mixture) to allow flexible handling

- Integrated APV25-S1 chip readout system
- 2D projective readout board, using laser etching and micro-machining



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Prototype triple-GEM configuration (2)



corresponding to ~385V-395V per GEM foil

• Testbeam effective gain: $\sim 3.5 \cdot 10^3$ ($\sim 2.5 \cdot 10^4$ bench tests)

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• Test beam configuration:

Top strips (Y): ~127µm

Bottom strips (X): 508µm

• Two separations: 25µm and 50µm

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Optical scans (1)



• Check for defects:

Missing holes, enlarged holes, dirt in holes and etching defects

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- 2D scanning table with CCD camera fully automated
- Scan GEM foils to measure hole diameter (inner and outer) and pitch









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GEM foil test results

Source tests (1)

- Two identical detectors, one with CERN foils, one using Tech-Etch foils
- Both detectors give reasonable X-Ray spectrum using ⁵⁵Fe source with comparable energy resolution (~20%)









 Evolution of relative gain for Tech-Etch and CERN GEM foil based triple-GEM prototype detector as a function of time O Irradiation: Low intensity ⁵⁵Fe source (~0.5Hz/

 mm^2)



Source tests (3)



O Gain measured with low intensity ⁵⁵Fe source $(~0.5Hz/mm^{2})$ O Good gain uniformity over full active area (Measured after charge built-up)

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O Comparison of optical scans of inner hole diameter uniformity and gain uniformity

from low-intensity ⁵⁵Fe source (~0.5Hz/mm²) measurements

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Source tests (5)



• Non-uniformity of inner hole diameter (~20µm smaller on left side compared to right side)

reflected in large non-uniformity of source scan gain measurements

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Testbeam results (1)





• FNAL Meson Test Beam Facility: Data taking with

4GeV-32GeV unseparated secondary beam and

120GeV primary proton beam

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GEM Control Unit

APV25-S1







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Testbeam results (3)



• Efficiencies at the level of ~95%-98% were reached in regions which limit the impact of noisy and dead regions with Tech-Etch GEM foils (Not affected by high intensity studies)

• Clear difference between Det0 (50µm) and Det 1 (25µm) for efficiency and cluster

amplitude (Most probable value of Landau distribution)

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Layout

- FGT: 6 light-weight disks
- Each disk consists of 4 triple-GEM chambers (Quarter sections)

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- Triple-GEM: Quarter section design (1)
 - Single disk
 - O 5mm Nomex honeycomb
 - O 0.25mm FR4 skins
 - Pins used as part of assembly and alignment
 - O GEM quadrant
 - O Pins define position
 - O Pins preserve shape
 - Gas manifolds and rails

Triple-GEM: Quarter section design (2)

Component	Material	Radiation Length [%]
Support plate	5 mm Nomex	0.040
	2x250 μm FR4	0.257
HV layer	5 μm Cu	0.035
	50 µm Kapton	0.017
GEM foils	6x5 μm Cu (70%)	0.147
	3x50 µm Kapton (70%)	0.036
Readout	5 µm Cu (20%)	0.007
	50 µm Kapton (20%)	0.003
	5 µm Cu (88%)	0.031
	50 µm Kapton	0.017
	5 μm Cu (10%)	0.004
	0.125 mm FR4	0.064
	5 µm Cu (10%)	0.004
Drift gas	10 mm CO ₂ (30%)	0.002
•	10 mm Ar (70%)	0.006
Total		0.670

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Triple-GEM: Quarter section design (3)

- 2-3mm thick
- Inner radius: 10.5cm
- O Outer radius: 38.1cm
- Flat at 31°
- 1mm gap between quadrants
- 4mm FR4 pins
- O 34 X 1mm holes for HV GEM foil

connection

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View at readout layer from downstream!

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Triple-GEM: Quarter section design (4)

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Triple-GEM: Quarter section design (5)

- Ο 50 μm Kapton
 - O Copper on both sides
 - Laser etching exposes bottom layer
- Top layer
 - O Φ -readout layer
 - O Alternate lines end at 18.8cm
 - O Pitch: 300-600 μm
 - O Line width: $80-120\mu m$
- Bottom layer
 - O R-readout layer
 - O Pitch: 800µm
 - O Line width: $700\mu m$

□ Triple-GEM: GEM foil design (1)

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Triple-GEM: GEM foil design (2)

Segmented GEM foils:

- Minimize damage in case of breakdown
- 9 segments in radial direction

with ~100cm² each

- Ο Gap: 200μm
- Hole pitch (~ 140µm) and

diameter (I: ~50µm /0: ~60µm)

similar to prototype!

- Routing and vias distribute HV
 - to segments

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Triple-GEM: GEM foils at MIT (1)

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Triple-GEM: GEM foils at MIT (2)

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Triple-GEM: GEM foil testing (1)

CCD camera setup for optical GEM foil scans (Glass plate modifications in progress)

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HV Vacuum / Nitrogen box for GEM foil dark current tests (Minor modifications necessary - In progress)

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Triple-GEM: GEM foil testing (2)

First scan for large GEM foil (Hole arrangement) First scan for large GEM foil (HV connection)

Triple-GEM: GEM foil stretching and assembly tooling

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Stretching jig:

- Stretch GEM foil
- Clamp 2mm spacer for single glue operation

Assembly jig:

- Align frames to each other and to SIMM pins
- Hold frames flat with clamps
- Hold SIMM pins in place
 for soldering
- Clamp frames together
 for gluing operation

Triple-GEM: 2D readout board design (1)

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Triple-GEM: 2D readout board design (2)

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Triple-GEM: 2D readout board design (3)

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Triple-GEM: Plans / Issues (Until June 2009)

- Finish tests of large GEM foils
- Charge sharing board assembly and test
- Finalize design of 2D readout board and order full scale 2D readout board prototype
- Assembly and test of full scale prototype (Source test and cosmic ray test setup)

Order of GEM foils and beginning of testing

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FEE: APV module

- Design of APV module completed
- Fabrication of APV module ongoing by Compunctics Inc.
- APV module will be used for test-charge board and full-scale prototype

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APV test module for multi-pin connector tests

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□ FEE: APV25-S1 chips at MIT

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FGT Schedule / Milestones

Overview - Planing

- Goal: Installation in summer 2010 ⇒ Ready for anticipated first long 500GeV polarized pp run in FY11 consistent with STAR 5-year Beam Use Request
- Review: Successful review January 2008 / Beginning of construction funds FY08
- Cost estimate and planing relies on the R&D and pre-design work:
 - Triple-GEM Detector: Complete prototype tested on the bench and during FNAL testbeam experiment with extensive experience in mechanical design work (MIT-Bates) and assembly including previous experience at COMPASS
 - Front-End Electronics (FEE) System: Complete prototype tested on the bench and during FNAL testbeam experiment based on existing APV25-S1 readout chip (MIT-Bates)
 - Data Acquisition (DAQ) System: Conceptual layout is based on similar DAQ sub-detector systems with extensive experience (ANL/IUCF)
 - GEM foil development: Successful development of industrially produced GEM foils through SBIR proposal in collaboration with Tech-Etch Inc. (BNL, MIT, Yale University)

Summary and Outlook

Summary

- Exciting program of W production in polarized proton-proton collisions at RHIC constraining unknown u/d anti-quark distributions
 Clear sensitivity in particular at forward rapidity
- STAR experiment requires upgrade of forward tracking system for charge sign discrimination of electrons/positrons
- Triple-GEM technology provides a cost effective way for a forward tracking upgrade solution
- Successful development of industrial production of GEM foils (SBIR proposal with Tech-Etch Inc.) - Test of large GEM foils ongoing
- Successful beam test at FNAL demonstrates that performance meets requirements
- Design work being finalized Pre-production underway
- Goal: Installation summer 2010 to be ready for Run 11

